74LVC2G241

Dual buffer/line driver; 3-state

Rev. 15 — 22 November 2018

Product data sheet

1. General description

The 74LVC2G241 is a dual non-inverting buffer/line driver with 3-state outputs. The 3-state outputs are controlled by the output enable inputs 1OE and 2OE:

- A HIGH level at pin $1\overline{\text{OE}}$ causes output 1Y to assume a high-impedance OFF-state.
- A LOW level at pin 2OE causes output 2Y to assume a high-impedance OFF-state.

Schmitt trigger action at all inputs makes the circuit highly tolerant of slower input rise and fall

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of the 74LVC2G241 as a translator in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
- JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
- HBM JESD22-A114F exceeds 2 000 V
 - MM JESD22-A115-A exceeds 200 V
- \pm 24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

| Type number | Package | Package | | | | | | | |
|--------------|-------------------|---------|---|----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| 74LVC2G241DP | -40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | SOT505-2 | | | | | |
| 74LVC2G241DC | -40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | SOT765-1 | | | | | |
| 74LVC2G241GT | -40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm | SOT833-1 | | | | | |
| 74LVC2G241GF | -40 °C to +125 °C | XSON8 | extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm | SOT1089 | | | | | |
| 74LVC2G241GM | -40 °C to +125 °C | XQFN8 | plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm | SOT902-2 | | | | | |
| 74LVC2G241GN | -40 °C to +125 °C | XSON8 | extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm | SOT1116 | | | | | |
| 74LVC2G241GS | -40 °C to +125 °C | XSON8 | extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm | SOT1203 | | | | | |

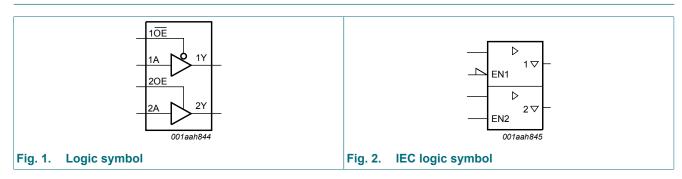
4. Marking

Table 2. Marking codes

| Type number | Marking code[1] |
|--------------|-----------------|
| 74LVC2G241DP | V241 |
| 74LVC2G241DC | V41 |
| 74LVC2G241GT | V41 |
| 74LVC2G241GF | V1 |
| 74LVC2G241GM | V41 |
| 74LVC2G241GN | V1 |
| 74LVC2G241GS | V1 |

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

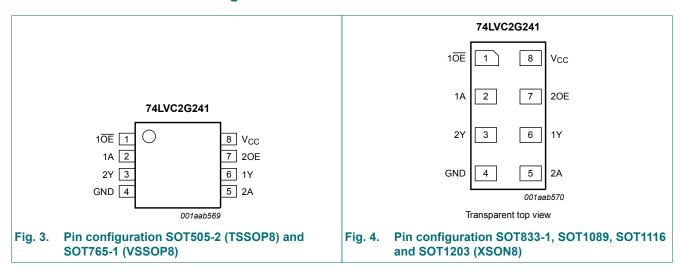
5. Functional diagram

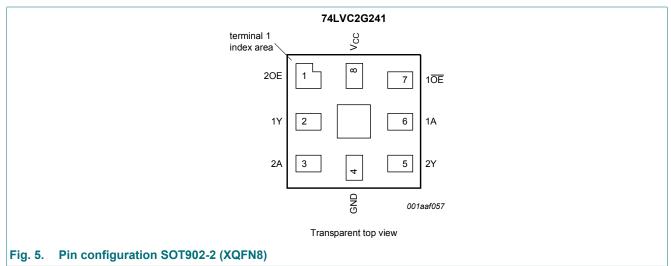


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6. Pinning information

6.1. Pinning





6.2. Pin description

Table 3. Pin description

| Symbol | Pin | | Description |
|-----------------|---|----------|-----------------------------------|
| | SOT505-2, SOT765-1, SOT833-1, SOT1089, SOT1116 and SOT1203 | SOT902-2 | |
| 1 OE | 1 | 7 | output enable input (active LOW) |
| 1A, 2A | 2, 5 | 6, 3 | data input |
| GND | 4 | 4 | ground (0 V) |
| 1Y, 2Y | 6, 3 | 2, 5 | data output |
| 20E | 7 | 1 | output enable input (active HIGH) |
| V _{CC} | 8 | 8 | supply voltage |

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7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

| Input 1 OE | | Output | | | |
|--------------------------|----|--------|----|----|----|
| 1 OE | 1A | 20E | 2A | 1Y | 2Y |
| L | L | Н | L | L | L |
| L | Н | Н | Н | Н | Н |
| Н | Х | L | Х | Z | Z |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|--------------------------------------|---------|------|-----------------------|------|
| V _{CC} | supply voltage | | | -0.5 | +6.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | | -50 | - | mA |
| VI | input voltage | | [1] | -0.5 | +6.5 | V |
| I _{OK} | output clamping current | $V_O > V_{CC}$ or $V_O < 0$ V | | - | ±50 | mA |
| Vo | output voltage | enable mode | [1] | -0.5 | V _{CC} + 0.5 | V |
| | | disable mode | [1] | -0.5 | +6.5 | V |
| | | Power-down mode | [1] [2] | -0.5 | +6.5 | V |
| Io | output current | $V_O = 0 V \text{ to } V_{CC}$ | | - | ±50 | mA |
| I _{CC} | supply current | | | - | 100 | mA |
| I _{GND} | ground current | | | -100 | - | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +125 °C | [3] | - | 300 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|---|------|-----------------|------|
| V _{CC} | supply voltage | | 1.65 | 5.5 | V |
| VI | input voltage | | 0 | 5.5 | V |
| V _O | output voltage | V _{CC} = 1.65 V to 5.5 V; enable mode | 0 | V _{CC} | V |
| | | V _{CC} = 1.65 V to 5.5 V; disable mode | 0 | 5.5 | V |
| | | V _{CC} = 0 V; Power-down mode | 0 | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 1.65 V to 2.7 V | - | 20 | ns/V |
| | | V _{CC} = 2.7 V to 5.5 V | - | 10 | ns/V |

^[2] When $V_{CC} = 0 \text{ V}$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

For TSSOP8 packages: above 55 °C the value of P_{tot} derates linearly at 2.5 mW/K. For VSSOP8 packages: above 110 °C the value of P_{tot} derates linearly at 8.0 mW/K.

For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ[1] | Max | Unit |
|--|---------------------------|---|------------------------|--------|------------------------|------|
| T _{amb} = - | 40 °C to +85 °C | | | 1 | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 1.65 V to 1.95 V | 0.65 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | - | - | V |
| | | V _{CC} = 2.7 V to 3.6 V | 2.0 | - | - | V |
| | | V _{CC} = 4.5 V to 5.5 V | 0.7 × V _{CC} | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 1.65 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 0.8 | V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 0.3 × V _{CC} | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V | - | - | 0.1 | V |
| | | I _O = 4 mA; V _{CC} = 1.65 V | - | - | 0.45 | V |
| | | I _O = 8 mA; V _{CC} = 2.3 V | - | - | 0.3 | V |
| | | I _O = 12 mA; V _{CC} = 2.7 V | - | - | 0.4 | V |
| | | I _O = 24 mA; V _{CC} = 3.0 V | - | - | 0.55 | V |
| | | I _O = 32 mA; V _{CC} = 4.5 V | - | - | 0.55 | V |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -4 mA; V _{CC} = 1.65 V | 1.2 | - | - | V |
| | | I _O = -8 mA; V _{CC} = 2.3 V | 1.9 | - | - | V |
| | | I _O = -12 mA; V _{CC} = 2.7 V | 2.2 | - | - | V |
| | | I _O = -24 mA; V _{CC} = 3.0 V | 2.3 | - | - | V |
| | | I _O = -32 mA; V _{CC} = 4.5 V | 3.8 | - | - | V |
| I _I | input leakage current | $V_{I} = 5.5 \text{ V or GND}; V_{CC} = 0 \text{ V to } 5.5 \text{ V}$ | - | ±0.1 | ±1 | μΑ |
| l _{OZ} | OFF-state output current | $V_I = V_{IH}$ or V_{IL} ; $V_O = 5.5$ V or GND; $V_{CC} = 3.6$ V | - | ±0.1 | ±2 | μΑ |
| I _{OFF} | power-off leakage current | V_{I} or $V_{O} = 5.5 \text{ V}$; $V_{CC} = 0 \text{ V}$ | - | ±0.1 | ±2 | μΑ |
| I _{CC} | supply current | V _I = 5.5 V or GND; I _O = 0 A; V _{CC} = 1.65 V to 5.5 V | - | 0.1 | 4 | μΑ |
| ΔI _{CC} | additional supply current | per pin; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 2.3 \text{ V}$ to 5.5 V | - | 5 | 500 | μΑ |
| Cı | input capacitance | | - | 2 | - | pF |
| T _{amb} = - | 40 °C to +125 °C | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 1.65 V to 1.95 V | 0.65 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | - | - | V |
| | | V _{CC} = 2.7 V to 3.6 V | 2.0 | - | - | V |
| I ₁ i Ioz C Ioff β Icc s ΔI _{CC} a T _{amb} = -40 | | V _{CC} = 4.5 V to 5.5 V | 0.7 × V _{CC} | - | - | V |

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| Symbol | Parameter | Conditions | Min | Typ[1] | Max | Unit |
|------------------|---------------------------|---|-----------------------|--------|------------------------|------|
| V_{IL} | LOW-level input voltage | V _{CC} = 1.65 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 0.8 | V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 0.3 × V _{CC} | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V | - | - | 0.1 | V |
| | | I _O = 4 mA; V _{CC} = 1.65 V | - | - | 0.70 | V |
| | | I _O = 8 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | I _O = 12 mA; V _{CC} = 2.7 V | - | - | 0.60 | ٧ |
| | | I _O = 24 mA; V _{CC} = 3.0 V | - | - | 0.80 | V |
| | | I _O = 32 mA; V _{CC} = 4.5 V | - | - | 0.80 | ٧ |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V | V _{CC} - 0.1 | - | - | ٧ |
| | | I _O = -4 mA; V _{CC} = 1.65 V | 0.95 | - | - | V |
| | | I_{O} = -8 mA; V_{CC} = 2.3 V | 1.7 | - | - | ٧ |
| | | I _O = -12 mA; V _{CC} = 2.7 V | 1.9 | - | - | V |
| | | I _O = -24 mA; V _{CC} = 3.0 V | 2.0 | - | - | V |
| | | I _O = -32 mA; V _{CC} = 4.5 V | 3.4 | - | - | V |
| I _I | input leakage current | $V_{I} = 5.5 \text{ V or GND}; V_{CC} = 0 \text{ V to } 5.5 \text{ V}$ | - | - | ±1 | μΑ |
| I _{OZ} | OFF-state output current | $V_I = V_{IH}$ or V_{IL} ; $V_O = 5.5$ V or GND; $V_{CC} = 3.6$ V | - | - | ±2 | μA |
| I _{OFF} | power-off leakage current | V _I or V _O = 5.5 V; V _{CC} = 0 V | - | - | ±2 | μΑ |
| I _{CC} | supply current | V _I = 5.5 V or GND; I _O = 0 A; V _{CC} = 1.65 V to 5.5 V | - | - | 4 | μΑ |
| ΔI _{CC} | additional supply current | per pin; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 2.3 \text{ V}$ to 5.5 V | - | - | 500 | μΑ |

^[1] Typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

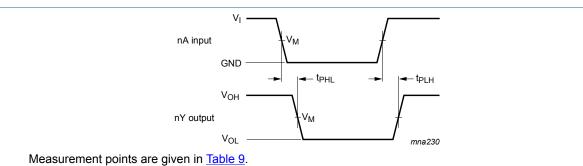
| Symbol | Parameter | Conditions | -40 | °C to +85 ° | С | -40 °C to | +125 °C | Unit |
|-----------------|-------------------|------------------------------------|-----|-------------|-----|-----------|---------|------|
| | | | Min | Typ[1] | Max | Min | Max | |
| t _{pd} | propagation delay | nA to nY; see Fig. 6 [2] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.0 | 4.5 | 8.8 | 1.0 | 11.0 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 0.5 | 2.8 | 4.9 | 0.5 | 6.3 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 2.8 | 4.7 | 1.0 | 5.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 0.5 | 2.6 | 4.3 | 0.5 | 5.4 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 2.1 | 3.7 | 0.5 | 4.6 | ns |

| Symbol Par | Parameter | Conditions | -40 | °C to +85 ° | C. | -40 °C to | Unit | |
|------------------|----------------------------------|--|-----|-------------|------|-----------|------|----|
| | | | Min | Typ[1] | Max | Min | Max | _ |
| t _{en} | enable time | 1 OE to 1Y; see <u>Fig. 7</u> [2] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.5 | 5.2 | 9.9 | 1.5 | 12.4 | ns |
| | V _{CC} = 2.3 V to 2.7 V | 1.0 | 3.1 | 5.6 | 1.0 | 7.0 | ns | |
| | | V _{CC} = 2.7 V | 1.5 | 3.2 | 5.5 | 1.5 | 6.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 0.5 | 2.7 | 4.7 | 0.5 | 5.9 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 2.0 | 3.8 | 0.5 | 4.8 | ns |
| | | 2OE to 2Y; see Fig. 8 [2] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.0 | 4.3 | 8.8 | 1.0 | 11.0 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.0 | 2.7 | 4.7 | 1.0 | 5.9 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 2.7 | 4.6 | 1.0 | 5.8 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 2.5 | 4.1 | 1.0 | 5.1 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 1.9 | 3.3 | 0.5 | 4.1 | ns |
| t _{dis} | disable time | 1 OE to 1Y; see <u>Fig. 7</u> [2] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.0 | 3.2 | 11.6 | 1.0 | 14.1 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 0.5 | 2.2 | 5.8 | 0.5 | 7.6 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 2.8 | 4.6 | 1.0 | 5.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 2.6 | 4.4 | 1.0 | 5.7 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 2.0 | 3.4 | 0.5 | 4.6 | ns |
| | | 2OE to 2Y; see Fig. 8 [2] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.0 | 3.6 | 12.5 | 1.0 | 15.2 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 0.5 | 2.0 | 5.2 | 0.5 | 6.9 | ns |
| | | V _{CC} = 2.7 V | 1.5 | 3.2 | 4.9 | 1.5 | 6.3 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 2.8 | 4.2 | 1.0 | 5.4 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 2.0 | 3.3 | 0.5 | 4.4 | ns |
| C _{PD} | power dissipation | per buffer; V_I = GND to V_{CC} [3] | | | | | | |
| | capacitance | output enabled | - | 20 | - | - | - | pF |
| | | output disabled | - | 5 | - | - | - | pF |
| | | | | | | | | |

Typical values are measured at nominal V_{CC} and at T_{amb} = 25 °C. t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{en} is the same as t_{PZH} and t_{PZL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; C_L = supply voltage in V; C_L = number of inputs switching; C_L = supply voltage in V; C_L = supply voltage in V; C_L = number of inputs switching; C_L = supply voltage in V; C_L = number of inputs switching; C_L = supply voltage in V; C_L = number of inputs switching; C_L = supply voltage in V; C_L = number of inputs switching; C_L = supply voltage in V; C_L = number of inputs switching; C_L = supply voltage in V; C_L = number of inputs switching; C_L = number of outputs.

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11.1. Waveforms and test circuit

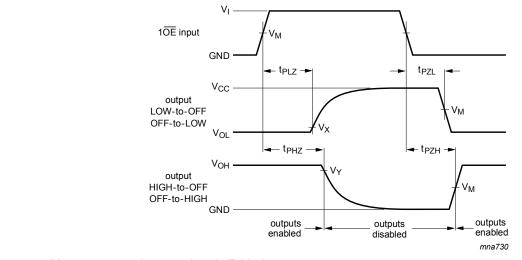


Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 6. The data input (nA) to output (nY) propagation delays

Table 9. Measurement points

| Supply voltage | Input | Output | | |
|------------------|-----------------------|-----------------------|--------------------------|--------------------------|
| V _{CC} | V _M | V _M | V _X | V _Y |
| 1.65 V to 1.95 V | 0.5 x V _{CC} | 0.5 x V _{CC} | V _{OL} + 0.15 V | V _{OH} - 0.15 V |
| 2.3 V to 2.7 V | 0.5 x V _{CC} | 0.5 x V _{CC} | V _{OL} + 0.15 V | V _{OH} - 0.15 V |
| 2.7 V | 1.5 V | 1.5 V | V _{OL} + 0.3 V | V _{OH} - 0.3 V |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V | V _{OL} + 0.3 V | V _{OH} - 0.3 V |
| 4.5 V to 5.5 V | 0.5 x V _{CC} | 0.5 x V _{CC} | V _{OL} + 0.3 V | V _{OH} - 0.3 V |

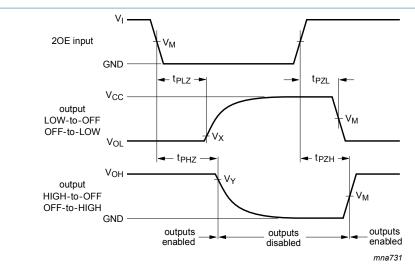


Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Enable and disable times for input 1 OE Fig. 7.

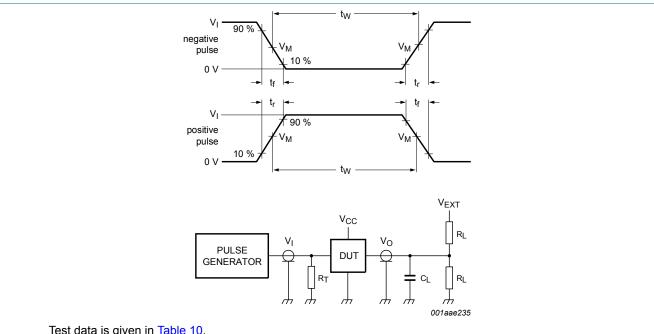
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Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Enable and disable times for input 20E Fig. 8.



Test data is given in Table 10.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance; R_L = Load resistance.

Test circuit for measuring switching times Fig. 9.

Table 10. Test data

| Supply voltage | Input | Load | | V _{EXT} | | |
|------------------|-----------------|-------|----------------|-------------------------------------|-------------------------------------|-------------------------------------|
| | V _I | CL | R _L | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} |
| 1.65 V to 1.95 V | V _{CC} | 30 pF | 1 kΩ | open | GND | 2 x V _{CC} |
| 2.3 V to 2.7 V | V _{CC} | 30 pF | 500 Ω | open | GND | 2 x V _{CC} |
| 2.7 V | 2.7 V | 50 pF | 500 Ω | open | GND | 6 V |
| 3.0 V to 3.6 V | 2.7 V | 50 pF | 500 Ω | open | GND | 6 V |
| 4.5 V to 5.5 V | V _{CC} | 50 pF | 500 Ω | open | GND | 2 x V _{CC} |

Dual buffer/line driver; 3-state

12. Package outline

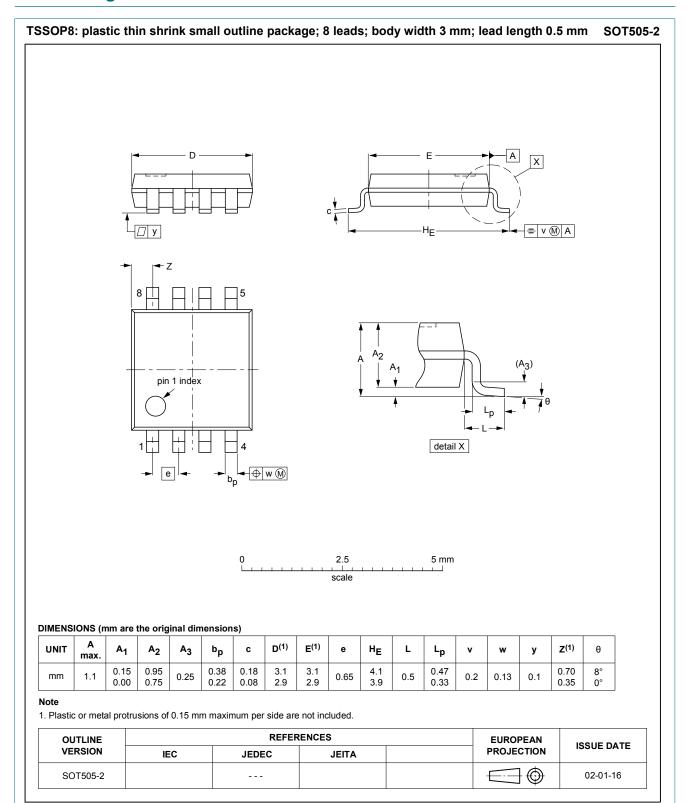


Fig. 10. Package outline SOT505-2 (TSSOP8)

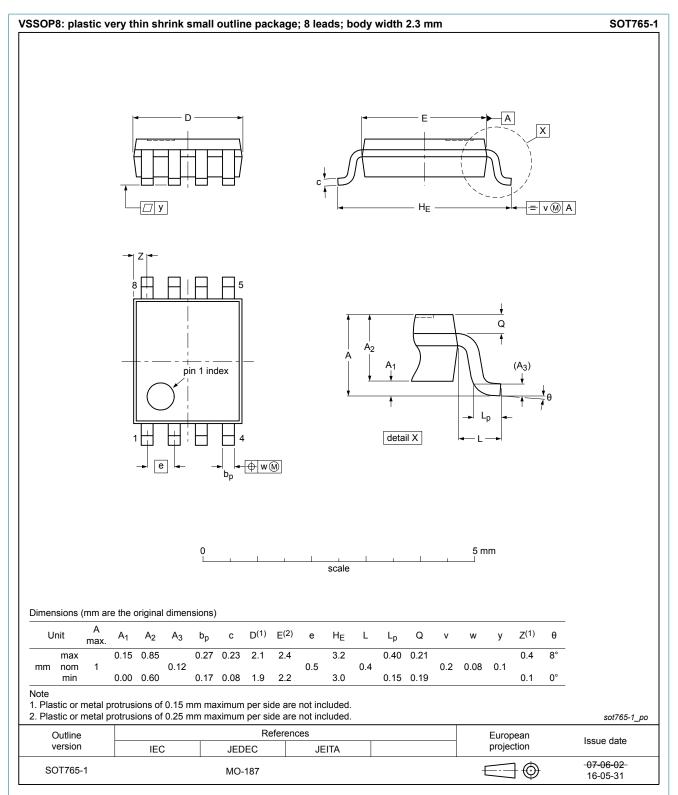


Fig. 11. Package outline SOT765-1 (VSSOP8)

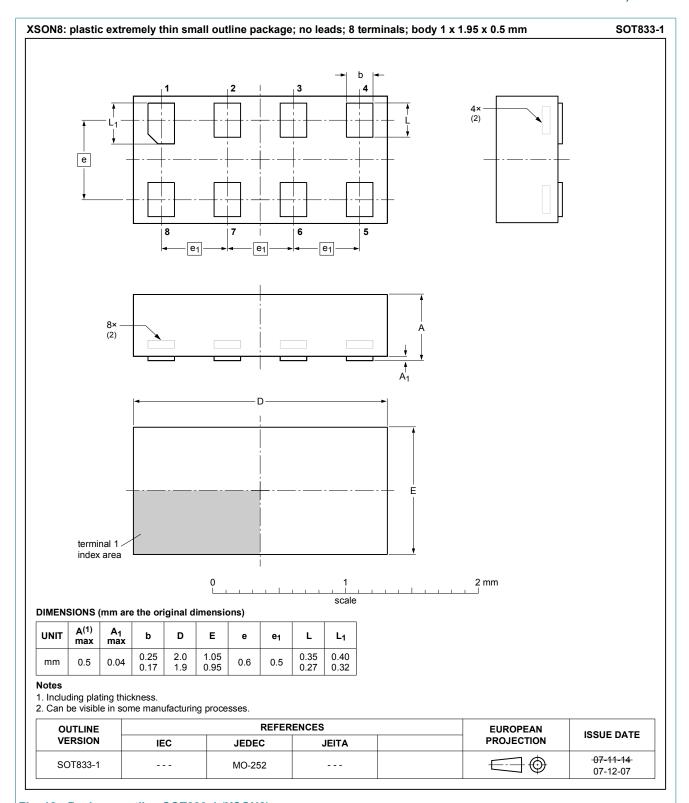


Fig. 12. Package outline SOT833-1 (XSON8)

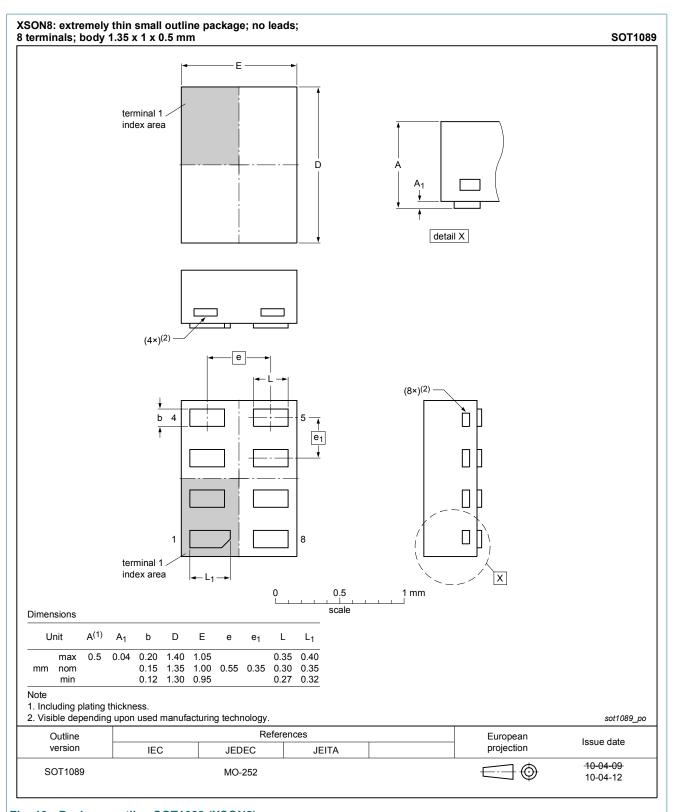


Fig. 13. Package outline SOT1089 (XSON8)

Dual buffer/line driver; 3-state

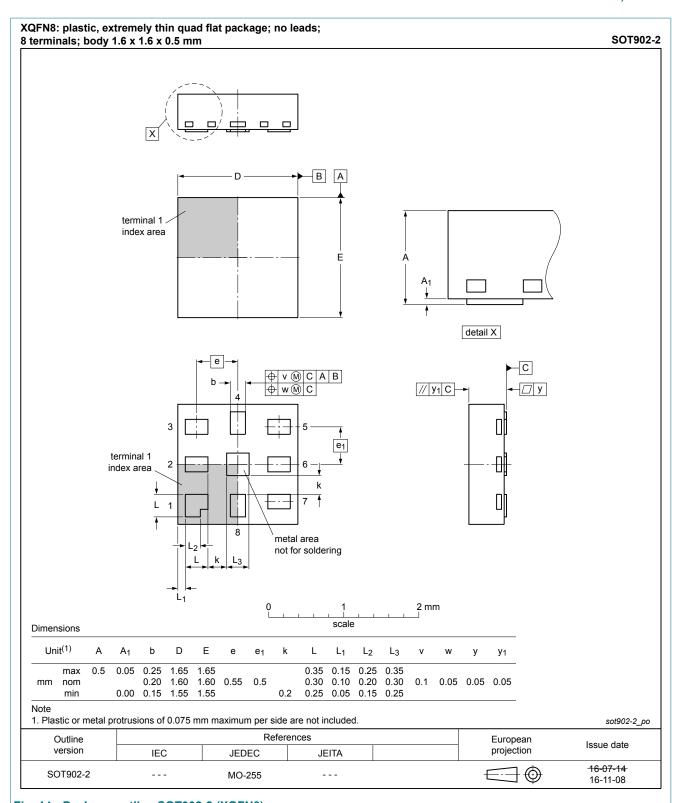


Fig. 14. Package outline SOT902-2 (XQFN8)

Product data sheet

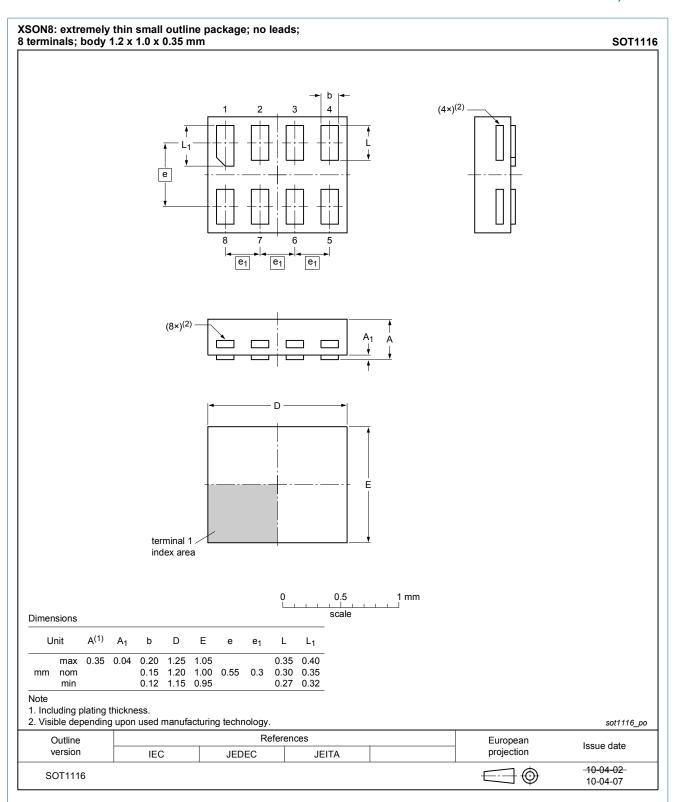


Fig. 15. Package outline SOT1116 (XSON8)

Dual buffer/line driver; 3-state

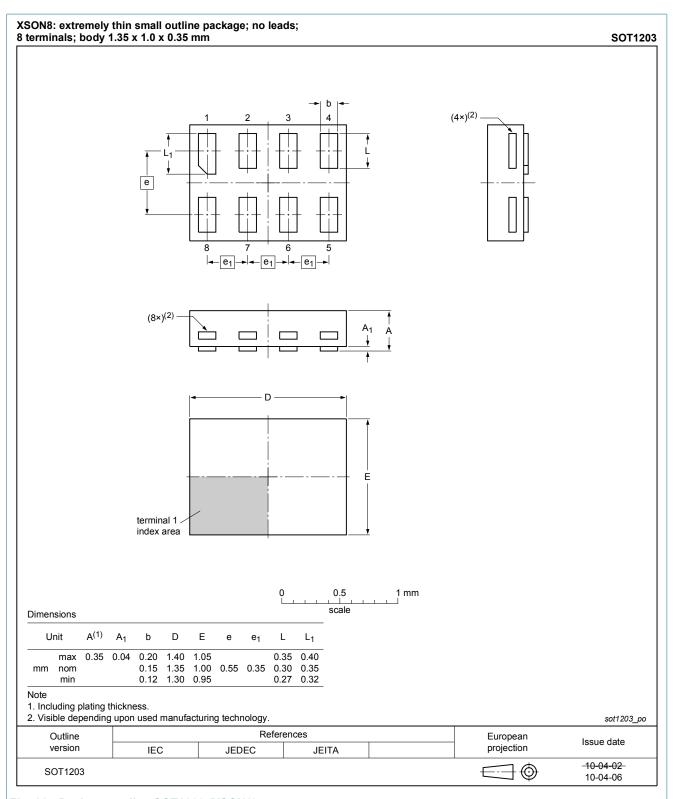


Fig. 16. Package outline SOT1203 (XSON8)

Product data sheet

Dual buffer/line driver; 3-state

13. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

14. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|-----------------|--|---|---------------|-----------------|--|--|
| 74LVC2G241 v.15 | 20181122 | Product data sheet | - | 74LVC2G241 v.14 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type numbers 74LVC2G241GD (SOT996-2/XSON8) removed. | | | | | |
| 74LVC2G241 v.14 | 20161215 | Product data sheet | - | 74LVC2G241 v.13 | | |
| Modifications: | <u>Table 7</u> : The maximum limits for leakage current and supply current have changed. | | | | | |
| 74LVC2G241 v.13 | 20130408 | Product data sheet | - | 74LVC2G241 v.12 | | |
| Modifications: | For type number 74 | For type number 74LVC2G241GD XSON8U has changed to XSON8. | | | | |
| 74LVC2G241 v.12 | 20120622 | Product data sheet | - | 74LVC2G241 v.11 | | |
| Modifications: | For type number 74LVC2G241GM the SOT code has changed to SOT902-2. | | | | | |
| 74LVC2G241 v.11 | 20111129 | Product data sheet | - | 74LVC2G241 v.10 | | |
| Modifications: | Legal pages updated. | | | | | |
| 74LVC2G241 v.10 | 20100806 | Product data sheet | - | 74LVC2G241 v.9 | | |
| 74LVC2G241 v.9 | 20080610 | Product data sheet | - | 74LVC2G241 v.8 | | |
| 74LVC2G241 v.8 | 20080312 | Product data sheet | - | 74LVC2G241 v.7 | | |
| 74LVC2G241 v.7 | 20071005 | Product data sheet | - | 74LVC2G241 v.6 | | |
| 74LVC2G241 v.6 | 20060922 | Product data sheet | - | 74LVC2G241 v.5 | | |
| 74LVC2G241 v.5 | 20050202 | Product specification | - | 74LVC2G241 v.4 | | |
| 74LVC2G241 v.4 | 20040922 | Product specification | - | 74LVC2G241 v.3 | | |
| 74LVC2G241 v.3 | 20030311 | Product specification | | 74LVC2G241 v.2 | | |
| 74LVC2G241 v.2 | 20030129 | Product specification | - | 74LVC2G241 v.1 | | |
| 74LVC2G241 v.1 | 20021030 | Product specification | - | - | | |

Dual buffer/line driver; 3-state

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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74LVC2G241

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Dual buffer/line driver; 3-state

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